Type OPB733TR

Features:

- Unfocused for sensing diffuse surfaces
- Uses lensed devices for collimation of light beam
- Low-cost plastic housing
- Compact surface mount package 0.300" x 0.160" x 0.114" [7.6mmx4.1mmx2.9mm]
- Typical peak emission wavelength 890nm
- Reduced visible ambient light sensitivity
- Optimal operating distance range 0.4" [10.2mm] to 1.0" [25.4mm]



Electronics

Description:

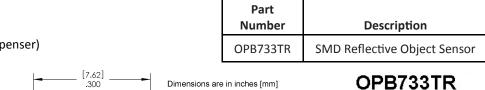
The OPB733TR consists of an 890nm, Infrared Light Emitting Diode (LED) and an NPN silicon Phototransistor, which are mounted "side-by-side" on parallel axes in a miniature surface mount grey plastic housing. The Phototransistor is molded in a grey epoxy package, which minimizes visible ambient light sensitivity. The phototransistor responds to radiation from the LED when a reflective object passes within its field of view. This unfocused reflective object sensor is ideal for non-contact detection of materials such as paper, labels, white plastic and many other reflective materials.

The OPB733TR sensors are packaged in 16mm tape on 7" [178mm] diameter reels, 500 pcs per reel. Tape and Reel package compatible with most automatic placement equipment.

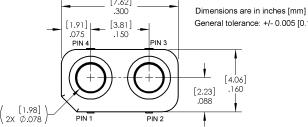
Custom electrical, PCB assembly, wire and connectors are available. Contact your local OPTEK authorized representative or OPTEK for more information. **Ordering Information**

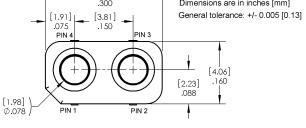
Applications:

- Assembly line automation
- ATM (Card Reader, Receipt Dispenser)
- Auto-dispense equipment
- Amusement equipment
- End-of-travel sensor
- Door sensor
- Edge detection
- Paper jam detection
- Mark detection
- Counters and sorters
- **Proximity sensing**
- Medical equipment



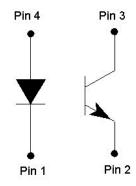
2X .165



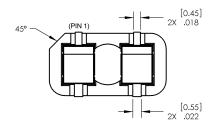


[2.89]

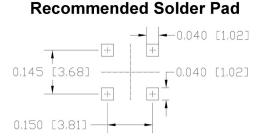
[0.27]



Pin #	Function			
1	Cathode			
2	Emitter			
3	Collector			
4	Anode			



[3.81]





Dimensions are in inches (mm)

General Note

Type OPB733TR



Absolute	Maximum Ratings (T _A = 25° C unless other	rwise no	oted)					
Storage	-25°C to +85°C							
Solderi	260° C							
Input LED								
Forwar	50 mA							
Peak F	1 A							
Revers	5 V							
Power	130 mW							
Output Ph	ototransistor							
Collect	30 V							
Emitte	5 V							
Collect	20 mA							
Power	75 mW							
Electrical	Characteristics (T _A = 25° C unless otherwis	e noted	l)					
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS		
Input IR LEC	(see OP271 for additional information)							
V _F	Forward Voltage	-	-	1.7	V	I _F = 20 mA		
I _R	Reverse Current	-	-	10	μΑ	V _R = 5 V		
θ_{HP}	Emission angle at half power points	-	25	-	Degree	I _F = 20 mA		
λ_{P}	Peak Emission Wavelength	-	890	-	nm	I _F = 10mA		
Output Ph	ototransistor (see OP571 for additional inform	ation)						
V _{(BR)CE0}	Collector Emitter Breakdown Voltage	30	-	-	V	Ι _C = 100 μΑ		
V _{(BR)ECO}	Emitter Collector Breakdown Voltage	5	-	-	v	Ι _Ε = 100 μΑ		
I _{CEO}	Collector Dark Current	-	-	100	nA	V _{CE} = 10 V, I _F = 0		
Tr	Rise Time	-	15	-	μs	$V_{CE} = 5 \text{ Volts}^{(3)}$)	
Tf	Fall Time	-	15	-	μs	$I_C = 1 \text{ mA}$ $R_L = 1 \text{K}\Omega$		
Coupled C	naracteristics					1		
V _{CE(SAT)}	Collector Emitter Saturation Voltage	-	-	0.4	V	d = 0.5" (12.7 mm) ⁽¹⁾⁽²⁾ I _C = 50 μA, I _F = 20 mA		
I _{C(ON)}	On-State Collector Current	0.1	-	-	mA	d = 0.5" (12.7 mm) ⁽¹⁾⁽²⁾ I _F = 20 mA, V _{CE} = 5 V		
Notes:							•	

Notes:

- 1. "d" is the distance from the assembly's top surface to the reflective surface.
- 2. Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface.
- 3. By designed but not tested.
- 4. Methanol or Isopropanol are recommended as cleaning agents. Plastic housing is soluble in chlorinated hydrocarbons and ketones.

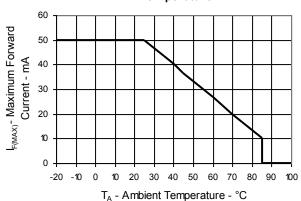
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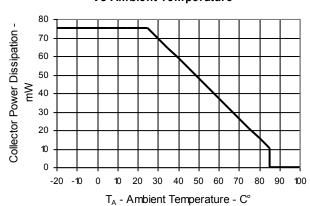


Typical Performance Curves

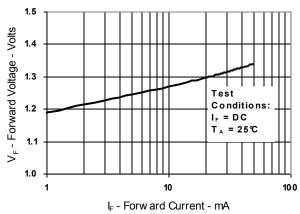
LED Maximum Forward Current Vs Ambient Temperature



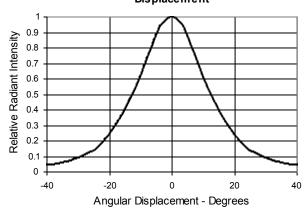
Phototransistor Collector Power Dissipation Vs Ambient Temperature



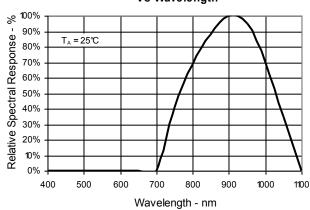
LED Forward Voltage Vs Forward Current



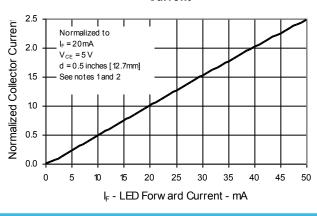
LED Relative Radiant Intensity Vs Angular Displacement



Phototransistor Relative Spectral Response Vs Wavelength



Normalized Collector Current Vs LED Forward Current

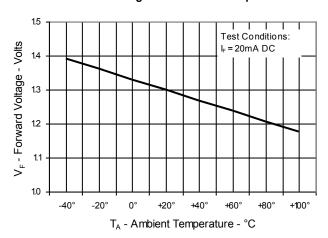


Type OPB733TR

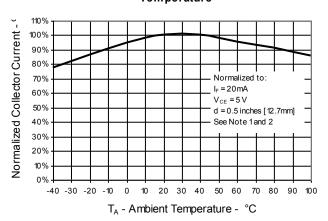


Typical Performance Curves

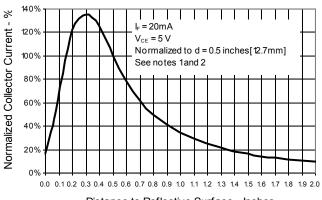
Forward Voltage Vs Ambient Temperature



Normalized Collector Current Vs Ambient Temperature



Normalized Collector Current Vs Object Distance



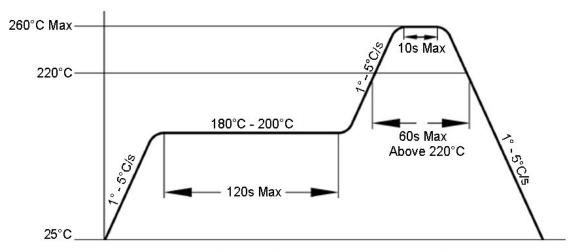
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Type OPB733TR



Soldering Method:

- Reflow soldering profile shown below. Soldering should not exceed this curve in temperature and time.
- Avoid soldering more than once.
- Avoid exerting any type of pressure on the optical lenses and contact leads before, during, and after soldering.



Lead Pb-free Reflow Solder Temperature Profile

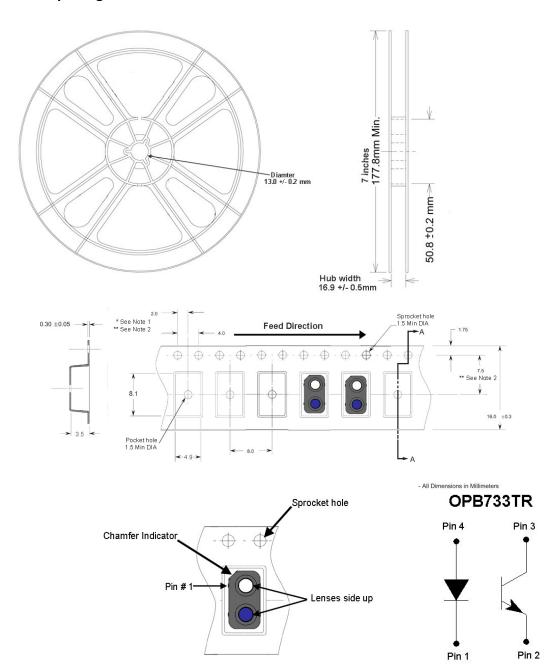
Storage:

- Storage temperature and relative humidity (R.H.) conditions are: 5°C to 30°C and 70% R.H. or less.
- Moisture proof bag should be open only if devices are ready to be used. Devices should be utilized within 72 hours after package has been opened.
- After opening the package, devices should be kept at a temperature of 5°C to 30°C and 60% R.H. or less.
- If the devices have exceed the storage time or the humidity card indicates 60% relative humidity level, all devices should go through a baking treatment outside the original package prior to usage. Baking treatment: 60°C +/- 5°C for 24 hours.

Type OPB733TR



Tape and Reel package dimensions:



Notes:

- 1. * 10 sprocket hole pitch cumulative tolerance +/- 0.2mm.
- 2. ** Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole.
- 3. Tolerances: +/- 0.1mm, except as noted.